

## Dielectric Properties of High-Q $(\text{Mg}_{1-x}\text{Zn}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$ Ceramics at Microwave Frequency

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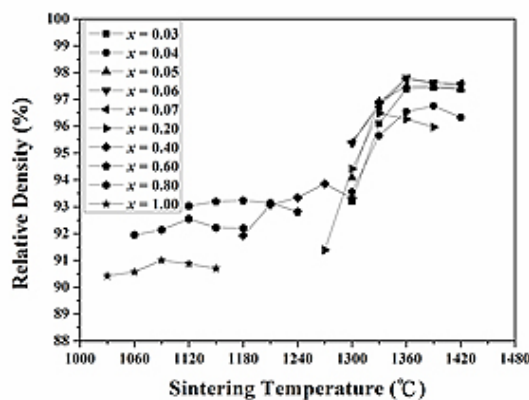
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$(\text{Mg}_{1-x}\text{Zn}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$  ( $x = 0.03-1.00$ ) ceramics were prepared via the conventional solid-state method and their dielectric properties were investigated in the microwave frequency region. Formation of solid solutions was confirmed by the X-ray diffraction analysis, the EDX analysis, and the measured lattice parameters. A small amount of Zn substitution for Mg produced a large increase in  $Q \times f$  due to a high packing fraction as well as a high relative density of the ceramics. By increasing  $x$  from 0.00 to 0.06, the  $Q \times f$  of the specimen could be tremendously improved from 141,000 to a maximum of 210,700 GHz (at 10.52 GHz), demonstrating an unique potential for low-loss microwave applications. The  $\tau_f$  values were found to retain in the range from  $-54.2$  to  $-62.3$  ppm/°C for all compositions because the resultant change of unit cell volume was small. Also, a remarkable lowering of the sintering temperature down to  $\sim 300$  °C was observed when Mg was totally substituted by Zn, thereby making it possible for low firing applications.

(a)



(b)

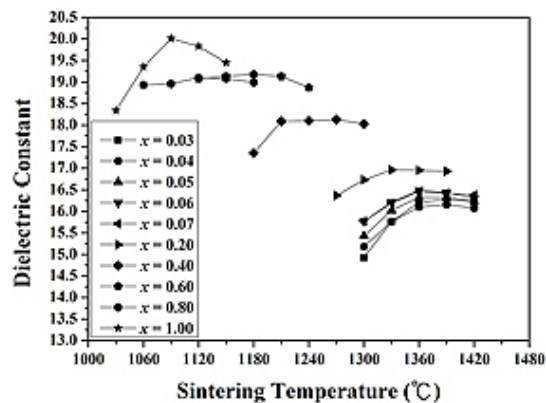
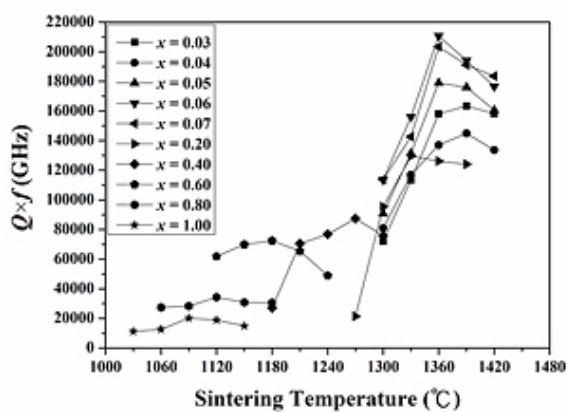


Fig. 1(a). Relative density of  $(\text{Mg}_{1-x}\text{Zn}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$  ( $x = 0.03-1.00$ ) ceramic system sintered at different temperatures for 4 h; Fig. 1(b). Dielectric constant of  $(\text{Mg}_{1-x}\text{Zn}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$  ( $x = 0.03-1.00$ ) ceramic system sintered at different temperatures for 4 h.

(a)



(b)

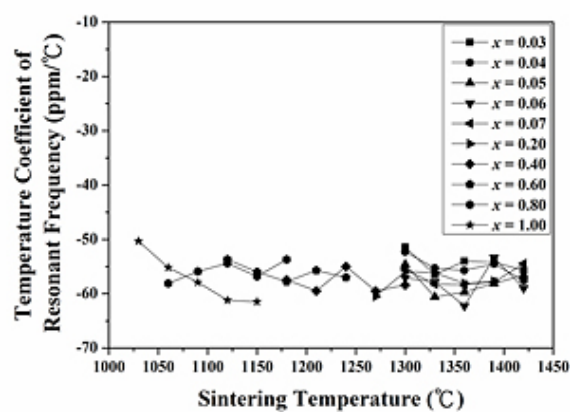


Fig. 2(a).  $Q \times f$  values of  $(\text{Mg}_{1-x}\text{Zn}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$  ( $x = 0.03-1.00$ ) ceramic system sintered at different temperatures for 4 h; Fig. 2(b).  $\tau_f$  values of  $(\text{Mg}_{1-x}\text{Zn}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$  ( $x = 0.03-1.00$ ) ceramic system sintered at different temperatures for 4 h.

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